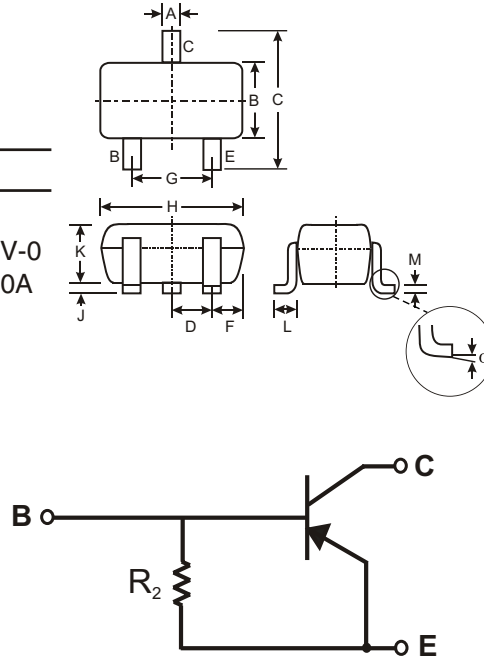


Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTC)
- Built-In Biasing Resistor, R2 only

Mechanical Data

- Case: SC-59, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.008 grams (approx.)
- Ordering Information (See Page 2)



SC-59		
Dim	Min	Max
A	0.35	0.50
B	1.50	1.70
C	2.70	3.00
D	0.95	
G	1.90	
H	2.90	3.10
J	0.013	0.10
K	1.00	1.30
L	0.35	0.55
M	0.10	0.20
α	0°	8°
All Dimensions in mm		

P/N	R2 (NOM)	MARKING
DDTA114KA	10K Ω	P26
DDTA124KA	22K Ω	P27
DDTA144KA	47K Ω	P28
DDTA115KA	100K Ω	P29

SCHMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _C (Max)	-100	mA
Power Dissipation	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625	°C/W
Operating and Storage and Temperature Range	T _j , T _{STG}	-55 to +150	°C

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.

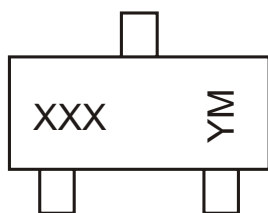
Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_{CBO}	-50	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage		BV_{CEO}	-50	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage		BV_{EBO}	5	—	—	V	$I_E = -720\mu\text{A}$, DDTA114GKA $I_E = -330\mu\text{A}$, DDTA124GKA $I_E = -160\mu\text{A}$, DDTA144GKA $I_E = -72\mu\text{A}$, DDTA115GKA
Collector Cutoff Current		I_{CBO}	—	—	-0.5	μA	$V_{CB} = -50\text{V}$
Emitter Cutoff Current	DDTA114KA DDTA124KA DDTA144KA DDTA115KA	I_{EBO}	-300 -140 -65 -30	—	-580 -260 -130 -58	μA	$V_{EB} = -4\text{V}$
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	—	—	-0.3	V	$I_C = -10\text{mA}$, $I_B = -0.5\text{mA}$
DC Current Transfer Ratio	DDTA114GKA DDTA124GKA DDTA144GKA DDTA115GKA	h_{FE}	30 56 68 82	—	—	—	$I_C = -5\text{mA}$, $V_{CE} = -5\text{V}$
Bleeder Resistor (R_2) Tolerance		DR_2	-30	—	+30	%	—
Gain-Bandwidth Product*		f_T	—	250	—	MHz	$V_{CE} = -10\text{V}$, $I_E = 5\text{mA}$, $f = 100\text{MHz}$

* Transistor - For Reference Only

Ordering Information (Note 2)

Device	Packaging	Shipping
DDTA114GKA-7	SC-59	3000/Tape & Reel
DDTA124GKA-7	SC-59	3000/Tape & Reel
DDTA144GKA-7	SC-59	3000/Tape & Reel
DDTA115GKA-7	SC-59	3000/Tape & Reel

Notes: 2. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.**Marking Information**

XXX = Product Type Marking Code
See Sheet 1 Diagrams
YM = Date Code Marking
Y = Year ex: N = 2002
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDTA114KA

NEW PRODUCT

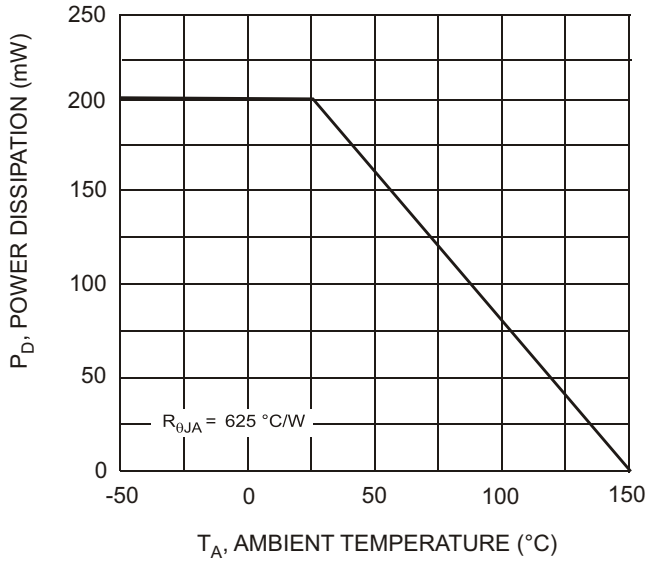


Fig. 1, Derating Curve

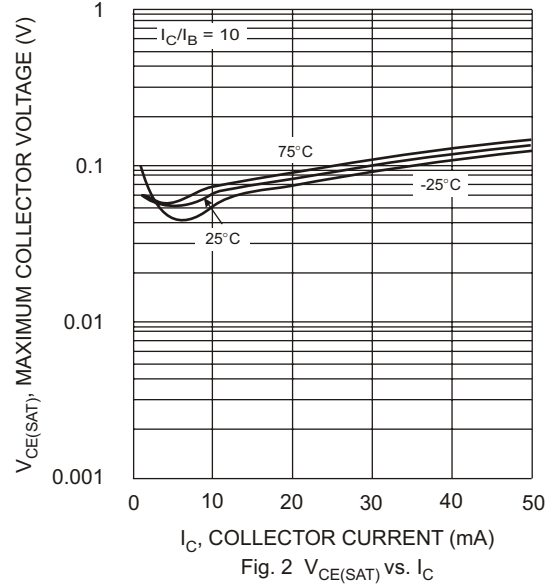


Fig. 2 $V_{CE(SAT)}$ vs. I_C

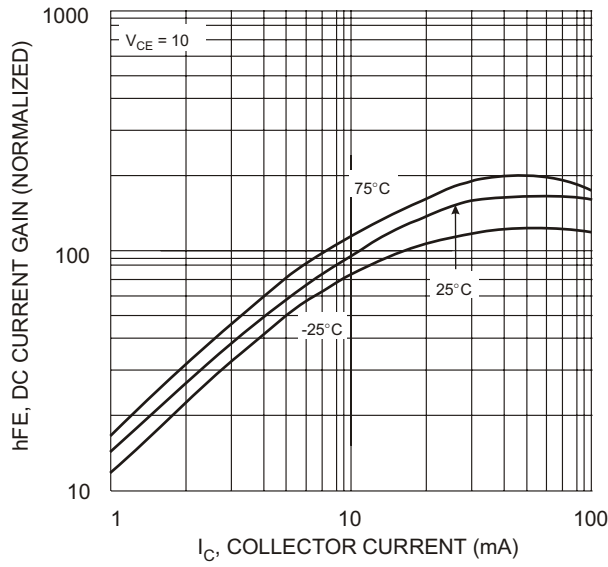


Fig. 3 DC CURRENT GAIN

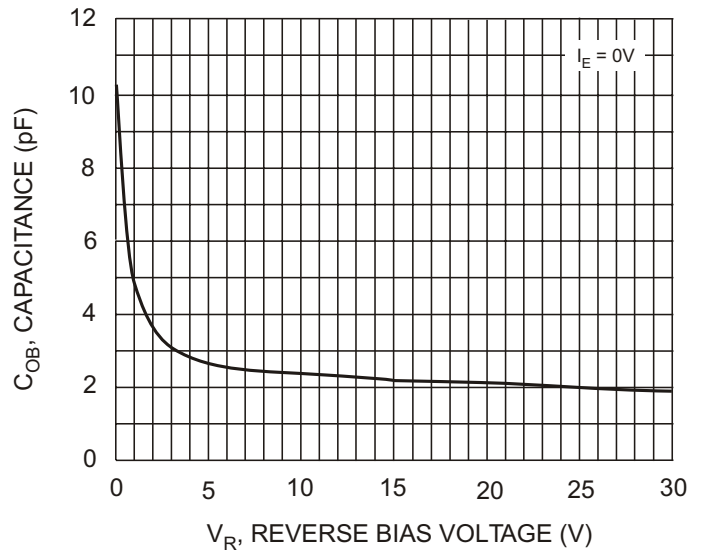


Fig. 4 Output Capacitance

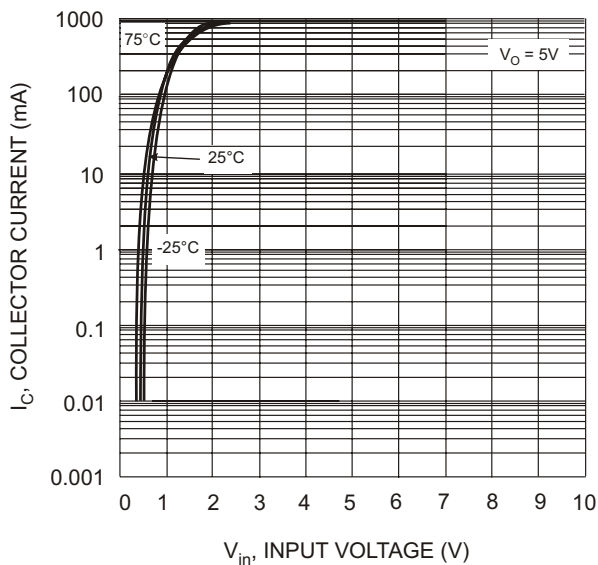


Fig. 5 Collector Current Vs. Input Voltage

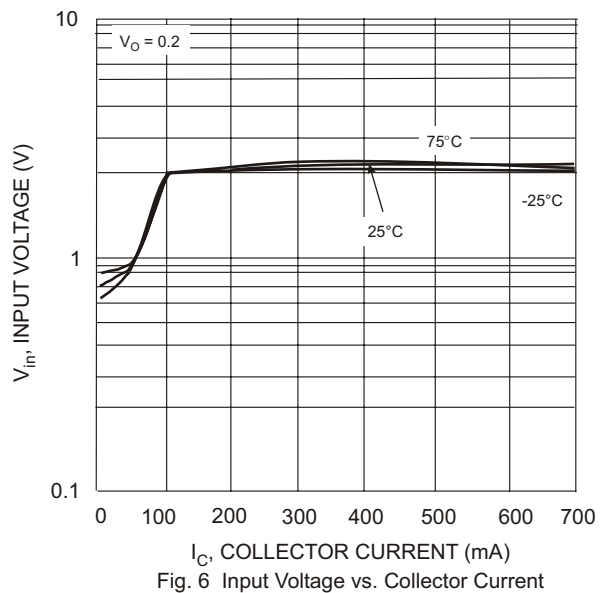


Fig. 6 Input Voltage vs. Collector Current